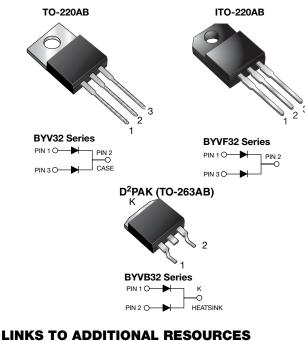
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## BYV32-xxx, BYVF32-xxx, BYVB32-xxx

Vishay General Semiconductor

# **Dual Common-Cathode Ultrafast Rectifier**





PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub>	18 A					
V <sub>RRM</sub>	50 V to 200 V					
I <sub>FSM</sub>	150 A					
t <sub>rr</sub>	25 ns					
V <sub>F</sub>	0.85 V					
T <sub>J</sub> max.	150 °C					
Package	TO-220AB, ITO-220AB, D <sup>2</sup> PAK (TO-263AB)					
Circuit configuration	Common cathode					

#### **FEATURES**

- Power pack
- · Glass passivated pellet chip junction
- Ultrafast recovery time
- · Low switching losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder dip 275 °C max. 10 s, per JESD 22-B106 (for TO-220AB and ITO-220AB package)
- AEC-Q101 qualified available - Automotive ordering code: base P/NHE3 (for ITO-220AB) base P/NHM3 (for D<sup>2</sup>PAK (TO-263AB package))
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### **TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, inverters, freewheeling diodes, DC/DC converters, and other power switching application.

#### **MECHANICAL DATA**

Case: TO-220AB, ITO-220AB, D<sup>2</sup>PAK (TO-263AB) Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Base P/NHE3\_X - RoHS-compliant and AEC-Q101 qualified

("\_X" denotes revision code e.g. A, B,....)

Base P/N-M3 - RoHS-compliant, halogen-free, commercial grade

Base P/NHM3 - RoHS-compliant, halogen-free, AEC-Q101 qualified

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 and M3 suffix meets JESD 201 class 1A whisker test, HE3 and HM3 suffix meets JESD 201 class 2 whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.



FREE

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<b>MAXIMUM RATINGS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	BYV32-50 BYVF32-50	BYV32-100 BYVF32-100	BYV32-150 BYVF32-150	BYV32-200 BYVF32-200 BYVB32-200	UNIT	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	V	
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	V	
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	V	
Maximum average forward rectified current at $T_C = 125 \text{ °C}$	I <sub>F(AV)</sub>	18				А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	I <sub>FSM</sub>	150				А	
Operating storage and temperature range	T <sub>J</sub> , T <sub>STG</sub>	-65 to +150				°C	
Isolation voltage (ITO-220AB only) from terminal to heatsink t = 1 min	V <sub>AC</sub>	1500				V	

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_c = 25 \text{ °C}$ unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	BYV32-50 BYVF32-50	BYV32-100 BYVF32-100	BYV32-150 BYVF32-150	BYV32-200 BYVF32-200 BYVB32-200	UNIT
Maximum instantaneous forward	$I_{F} = 20 \text{ A}$	$T_J = 25 \ ^\circ C$	V <sub>F</sub> <sup>(1)</sup>	1.15				v
voltage per diode	<sub>F</sub> = 5.0 A	$T_J = 100 \ ^\circ C$	VF V	0.85				
Maximum DC reverse current		$T_J = 25 \ ^\circ C$		10				μA
per diode at rated DC blocking voltage		T <sub>J</sub> = 100 °C	I <sub>R</sub>	600				
Maximum reverse recovery time per diode			t <sub>rr</sub>	25				ns
Typical junction capacitance per diode	4.0 V, 1 MHz		CJ	45				pF

Note

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<b>THERMAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	SYMBOL	BYV	BYVF	BYVB	UNIT		
Typical thermal resistance from junction to case per diode	$R_{ ext{ heta}JC}$	1.6	5.0	1.6	°C/W		

ORDERING INFORMATION (Example)								
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
TO-220AB	BYV32-200-E3/45	1.85	45	50/tube	Tube			
ITO-220AB	BYVF32-200-E3/45	1.97	45	50/tube	Tube			
D <sup>2</sup> PAK (TO-263AB)	BYVB32-200-M3/I	1.35	I	800/reel	Tape and reel			
ITO-220AB	BYVF32-200HE3_A/P (1)	1.97	Р	50/tube	Tube			
D <sup>2</sup> PAK (TO-263AB)	BYVB32-200HM3/I (1)	1.35	I	800/reel	Tape and reel			

Note

 $^{(1)}\,$  AEC-Q101 qualified, available in ITO-220AB and D^2PAK (TO-263AB) package

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### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

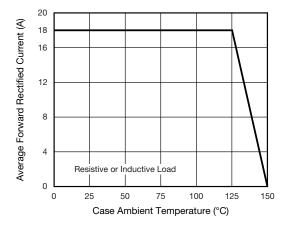


Fig. 1 - Forward Current Derating Curve

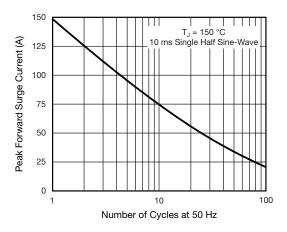


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

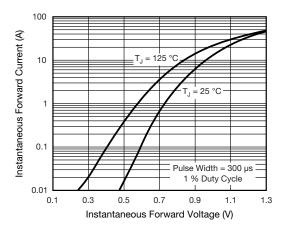


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

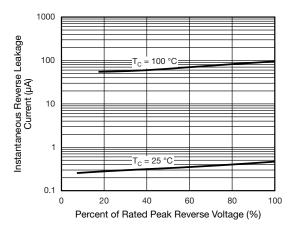


Fig. 4 - Typical Reverse Leakage Characteristics Per Diode

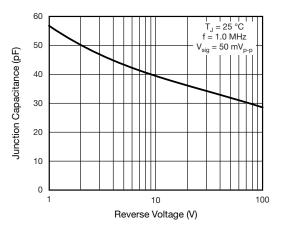


Fig. 5 - Typical Junction Capacitance Per Diode

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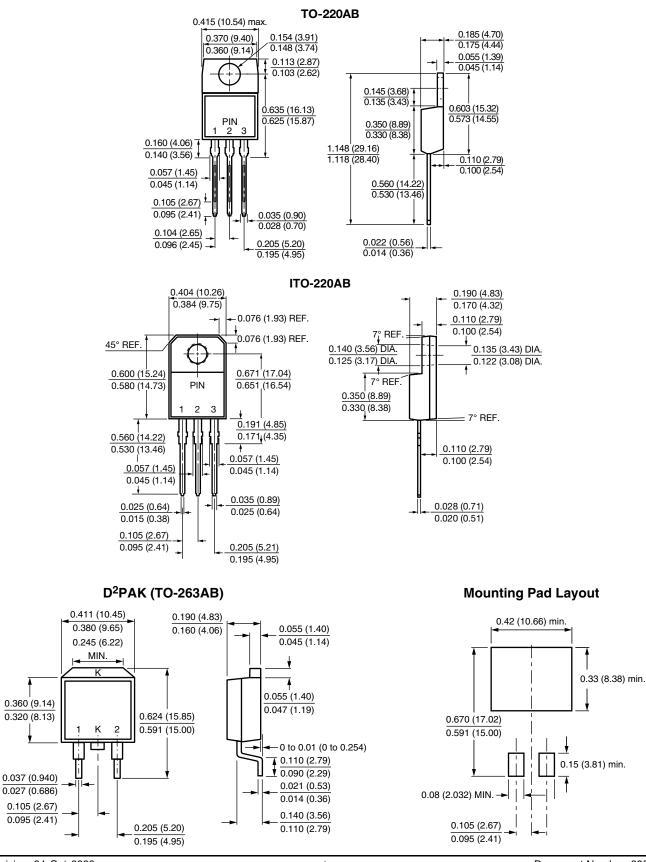
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#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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